

**AMENDMENTS TO THE CLAIMS**

Please replace all prior versions, and listings, of claims in the application with the following list of claims:

1. (Currently amended) A photovoltaic element comprising an ITO substrate coated with a metallic oxide layer or a derivative layer thereof as a transparent electrode, the metallic oxide layer or derivative layer being from 10nm to 100nm thick.
2. (Previously presented) The photovoltaic element according to claim 1, wherein the metallic oxide includes at least one element among Ti, Cu, Zn, As, Sr, Nb, Ib, Sn and W.
3. (Original) The photovoltaic element according to claim 1, wherein when the metallic oxide film is held for one hour in atmospheric air at 500°C, the rise of a resistance value is 10  $\Omega/\text{cm}^2$  or lower.
4. (Currently amended) The photovoltaic element according to claim 1, wherein a light transmittance of the ITO substrate coated with the metallic oxide in the wavelength range from 400 nm to 900 nm is 60% or higher.
5. (Previously presented) The photovoltaic element according to claim 1, further comprising a metallic oxide semiconductor carrying a dye as an electrode of a dye-sensitized type solar cell.